



TS3A44159 0.45-Ω Quad SPDT Analog Switch 4-Channel 2:1 Multiplexer – Demultiplexer With Two Controls

1 Features

- Specified Break-Before-Make Switching
- Low ON-State Resistance ($<0.5\ \Omega$)
- Control Inputs Are 1.8-V Logic Compatible
- Low Charge Injection
- Excellent ON-State Resistance Matching
- Low Total Harmonic Distortion (THD)
- 1.65-V to 4.3-V Single-Supply Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - ± 2000 -V Human-Body Model (A114-B, Class II)
 - ± 1000 -V Charged-Device Model (C101)

2 Applications

- Cell Phones
- PDA's
- Portable Instrumentation
- Audio and Video Signal Routing
- Low-Voltage Data-Acquisition Systems
- Communication Circuits
- Modems
- Hard Drives
- Computer Peripherals
- Wireless Pins and Peripherals

3 Description

The TS3A44159 is a bidirectional 4-channel single-pole double-throw (SPDT) analog switch with two control inputs, which is designed to operate from 1.65 V to 4.3 V. This device is also known as a 2 channel double-pole double-throw (DPDT) configuration. It offers low ON-state resistance and excellent ON-state resistance matching with the break-before-make feature that prevents signal distortion during the transferring of a signal from one channel to another. The device has an excellent total harmonic distortion (THD) performance and consumes very low power. These features make this device suitable for portable audio applications

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TS3A44159	TSSOP (16)	5.00 mm × 4.40 mm
	VQFN (16)	3.00 mm × 3.00 mm
	UQFN (16)	2.60 mm × 1.80 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Simplified Schematic

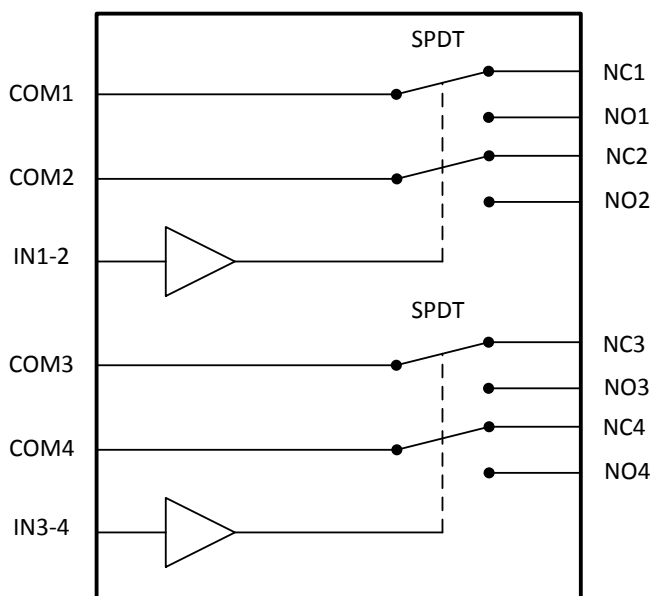


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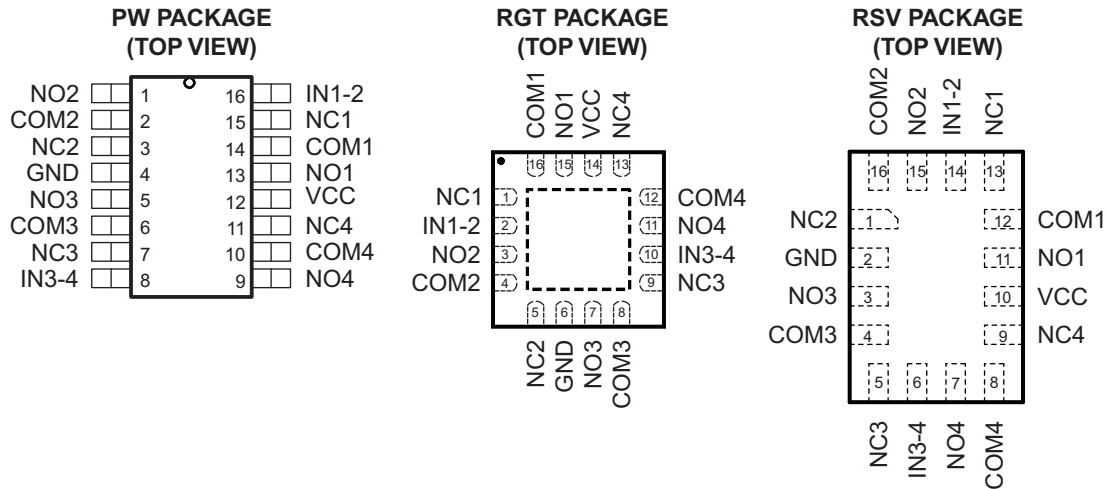
4 Revision History

Changes from Revision B (October 2012) to Revision C

Page

- Added *Pin Configuration and Functions* section, *ESD Ratings* table, *Feature Description* section, *Device Functional Modes*, *Application and Implementation* section, *Power Supply Recommendations* section, *Layout* section, *Device and Documentation Support* section, and *Mechanical, Packaging, and Orderable Information* section **1**

5 Pin Configuration and Functions



Pin Functions

PIN				I/O	DESCRIPTION
PW NO.	RGT NO.	RSV NO.	NAME		
1	3	15	NO2	I/O	Normally Open
2	4	16	COM2	I/O	Common
3	5	1	NC2	I/O	Normally Closed
4	6	2	GND	—	Ground
5	7	3	NO3	I/O	Normally Open
6	8	4	COM3	I/O	Common
7	9	5	NC3	I/O	Normally Closed
8	10	6	IN3-4	I	Digital Control to connect COM to NO or NC
9	11	7	NO4	I/O	Normally Open
10	12	8	COM4	I/O	Common
11	13	9	NC4	I/O	Normally Closed
12	14	10	VCC	I	Power Supply
13	15	11	NO1	I/O	Normally Open
14	16	12	COM1	I/O	Common
15	1	13	NC1	I/O	Normally Closed
16	2	14	IN1-2	I/O	Digital Control to connect COM to NO or NC

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)^{(1) (2)}

			MIN	MAX	UNIT
V _{CC}	Supply voltage ⁽³⁾		−0.5	4.6	V
V _{NC} V _{NO} V _{COM}	Analog voltage ^{(3) (4) (5)}		−0.5	V _{CC} + 0.5	V
I _K	Analog port diode current	V _{NC} , V _{NO} , V _{COM} < 0	−50		mA
I _{NC} I _{NO} I _{COM}	ON-state switch current ON-state peak switch current ⁽⁶⁾	V _{NC} , V _{NO} , V _{COM} = 0 to V _{CC}	−200 −400	200 400	mA
V _{IN}	Digital input voltage		−0.5	4.6	V
I _{IK}	Digital input clamp current ^{(3) (4)}	V _I < 0	−50		mA
I _{CC}	Continuous current through V _{CC}			100	mA
I _{GND}	Continuous current through GND		−100		mA
T _{stg}	Storage temperature		−65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
- (3) All voltages are with respect to ground, unless otherwise specified.
- (4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (5) This value is limited to 4.6 V maximum.
- (6) Pulse at 1-ms duration <10% duty cycle

6.2 ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _{CC}	Supply Voltage	0	4.3	V
V _{NC} V _{NO} V _{COM}	Analog Voltage	0	4.3	V
V _{IN}	Digital Input Voltage	0	4.3	V

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TS3A44159			UNIT
		PW	RGT	RSV	
		16 PINS			
R _{θJA}	Junction-to-ambient thermal resistance	108.0	45.4	107.1	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	43.0	58.1	41.2	
R _{θJB}	Junction-to-board thermal resistance	53.1	18.6	43.6	
Ψ _{JT}	Junction-to-top characterization parameter	4.6	1.1	1.1	
Ψ _{JB}	Junction-to-board characterization parameter	52.5	18.6	43.6	
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	3.9	N/A	

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

6.5 Electrical Characteristics for 1.8-V Supply

V_{CC} = 1.65 V to 1.95 V, T_A = –40°C to 85°C (unless otherwise noted)⁽¹⁾

PARAMETER		TEST CONDITIONS		T _A	V _{CC}	MIN	TYP	MAX	UNIT
ANALOG SWITCH									
V _{COM} , V _{NO} , V _{NC}	Analog signal range					0		V _{CC}	V
R _{on}	ON-state resistance	V _{NO} or V _{NC} = 1.5 V, I _{COM} = −100 mA,	Switch ON, See Figure 16	25°C	1.65 V	0.5	0.7		Ω
				Full			0.8		
ΔR _{on}	ON-state resistance match between channels	V _{NO} or V _{NC} = 1.5 V, 0.6 V I _{COM} = −100 mA,	Switch ON, See Figure 16	25°C	1.65 V	0.05	0.07		Ω
				Full			0.1		
R _{on(flat)}	ON-state resistance flatness	V _{NO} or V _{NC} = 1.5 V, 0.6 V 1.5 V, 2.5 V, I _{COM} = −100 mA,	Switch ON, See Figure 16	25°C	1.65 V	0.5	0.7		Ω
				Full			0.8		
I _{NO(OFF)} , I _{NC(OFF)}	NC, NO OFF leakage current	V _{NO} or V _{NC} = 0.3 V, V _{COM} = 1.65 V, or V _{NO} or V _{NC} = 1.65 V, V _{COM} = 0.3 V,	See Figure 17	25°C	1.95 V	−10	0.5	10	nA
				Full			−20	20	
I _{NO(ON)} , I _{NC(ON)}	NC, NO ON leakage current	V _{NO} or V _{NC} = 0.3 V, V _{COM} = Open, or V _{NO} or V _{NC} = 1.65 V, V _{COM} = Open,	See Figure 18	25°C	1.95 V	−10	0.1	10	nA
				Full			−20	20	
I _{COM(ON)}	COM ON leakage current	V _{NO} or V _{NC} = Open, V _{COM} = 0.3V, or V _{NO} or V _{NC} = Open, V _{COM} = 1.65 V,	See Figure 18	25°C	1.95 V	−10	0.1	10	nA
				Full			−20	20	
DIGITAL CONTROL INPUTS (IN1-2, IN3-4) ⁽²⁾									
V _{IH}	Input logic high			Full		1		4.3	V
V _{IL}	Input logic low			Full		0		0.4	V
I _{IH} , I _{IL}	Input leakage current	V _{IN} = 3.6 V or 0		25°C	1.95 V	0.5		10	nA
				Full				50	
DYNAMIC									
t _{ON}	Turn-on time	V _{COM} = V _{CC} , R _L = 50 Ω,	C _L = 35 pF	25°C	1.8 V	40		70	ns
				Full	1.65 V to 1.95 V			75	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(2) All unused digital inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, [SCBA004](#).

Electrical Characteristics for 1.8-V Supply (continued)

 $V_{CC} = 1.65\text{ V to }1.95\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)⁽¹⁾

PARAMETER	TEST CONDITIONS	T_A	V_{CC}	MIN	TYP	MAX	UNIT
t_{OFF} Turn-off time	$V_{COM} = V_{CC}$, $R_L = 50\ \Omega$, $C_L = 35\text{ pF}$	25°C	1.8 V		22	45	ns
		Full	1.65 V to 1.95 V			50	
t_{BBM} Break-before-make time	$V_{NC} = V_{NO} = V_{CC}$, $R_L = 50\ \Omega$, $C_L = 35\text{ pF}$	25°C	1.8 V	5	25	70	ns
		Full	1.65 V to 1.95 V	4		75	
Q_C Charge injection	$V_{GEN} = 0$, $R_{GEN} = 0$, $C_L = 1\text{ nF}$	25°C	1.8 V		64		pC
$C_{NC(OFF)}$, $C_{NO(OFF)}$ NC, NO OFF capacitance	V_{NC} or $V_{NO} = V_{CC}$ or GND, Switch OFF, See Figure 19	25°C	1.8 V		52		pF
$C_{NC(ON)}$, $C_{NO(ON)}$ NC, NO ON capacitance	V_{NC} or $V_{NO} = V_{CC}$ or GND, Switch OFF, See Figure 19	25°C	1.8 V		164		pF
$C_{COM(ON)}$ COM ON capacitance	$V_{COM} = V_{CC}$ or GND, Switch ON, See Figure 19	25°C	1.8 V		164		pF
C_I Digital input capacitance	$V_I = V_{CC}$ or GND	25°C	1.8 V		2.5		pF
BW Bandwidth	$R_L = 50\ \Omega$, Switch ON	25°C	1.8 V		35		MHz
O_{ISO} OFF isolation	$R_L = 50\ \Omega$, $f = 100\text{ kHz}$, Switch OFF	25°C	1.8 V		-71		dB
X_{TALK} Crosstalk	$R_L = 50\ \Omega$, $f = 100\text{ kHz}$, Switch ON	25°C	1.8 V		-73		dB
THD Total harmonic distortion	$R_L = 600\ \Omega$, $C_L = 50\text{ pF}$, $V_{COM} = \text{GND to } V_{CC}$, $f = 20\text{ Hz to } 20\text{ kHz}$	25°C	1.8 V		0.1%		
SUPPLY							
I_{CC} Positive supply current	$V_I = V_{CC}$ or GND, Switch ON or OFF	25°C	1.95 V		0.001	0.05	μA
		Full				0.15	

6.6 Electrical Characteristics for 2.1-V Supply

 $V_{CC} = 2.00\text{ V to }2.20\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)⁽¹⁾

PARAMETER	TEST CONDITIONS	T_A	V_{CC}	MIN	TYP	MAX	UNIT
DIGITAL CONTROL INPUTS (IN1-2, IN3-4)							
V_{IH} Input logic high		Full		1.2		4.3	V
V_{IL} Input logic low		Full		0		0.5	V

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

6.7 Electrical Characteristics for 2.5-V Supply

 $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$, $T_A = -40^\circ\text{C to } 85^\circ\text{C}$ (unless otherwise noted)⁽¹⁾

PARAMETER		TEST CONDITIONS		T _A	V _{CC}	MIN	TYP	MAX	UNIT
ANALOG SWITCH									
V _{COM} , V _{NO} , V _{NC}	Analog signal range					0		V _{CC}	V
R _{on}	ON-state resistance	V _{NO} or V _{NC} = 1.8 V, I _{COM} = −100 mA,	Switch ON, See Figure 16	25°C Full	2.3 V	0.45	0.6	0.7	Ω
ΔR _{on}	ON-state resistance match between channels	V _{NO} or V _{NC} = 1.8 V, 0.8 V, I _{COM} = −100 mA,	Switch ON, See Figure 16	25°C Full	2.3 V	0.045	0.07	0.1	Ω
R _{on(flat)}	ON-state resistance flatness	V _{NO} or V _{NC} = 1.8 V, 0.8 V I _{COM} = −100 mA,	Switch ON, See Figure 16	25°C Full	2.3 V	0.06	0.15	0.2	Ω
I _{NO(OFF)} , I _{NC(OFF)}	NC, NO OFF leakage current	V _{NO} or V _{NC} = 0.3 V, V _{COM} = 2.3 V, or V _{NO} or V _{NC} = 2.3 V, V _{COM} = 0.3V,	See Figure 17	25°C Full	2.7 V	−10 −20	0.5	10 20	nA
I _{NO(ON)} , I _{NC(ON)}	NC, NO ON leakage current	V _{NO} or V _{NC} = 0.3 V, V _{COM} = Open, or V _{NO} or V _{NC} = 2.3 V, V _{COM} = Open,	See Figure 18	25°C Full	2.7 V	−10 −20	0.1	10 20	nA
I _{COM(ON)}	COM ON leakage current	V _{NO} or V _{NC} = Open, V _{COM} = 0.3 V, or V _{NO} or V _{NC} = Open, V _{COM} = 2.3 V,	See Figure 18	25°C Full	2.7 V	−10 −20	0.1	10 20	nA
DIGITAL CONTROL INPUTS (IN1-2, IN3-4) ⁽²⁾									
V _{IH}	Input logic high			Full		1.2		4.3	V
V _{IL}	Input logic low			Full		0		0.6	V
I _{IH} , I _{IL}	Input leakage current	V _{IN} = 3.6 V or 0		25°C Full	2.7 V	0.5		10 50	nA
DYNAMIC									
t _{ON}	Turn-on time	V _{COM} = V _{CC} , R _L = 50 Ω,	C _L = 35 pF	25°C Full	2.5 V 2.3 V to 2.7 V	2.6		47 50	ns
t _{OFF}	Turn-off time	V _{COM} = V _{CC} , R _L = 50 Ω,	C _L = 35 pF	25°C Full	2.5 V 2.3 V to 2.7 V	16.5		34 35	ns
t _{BBM}	Break-before-make time	V _{NC} = V _{NO} = V _{CC} , R _L = 50 Ω,	C _L = 35 pF	25°C Full	2.5 V 2.3 V to 2.7 V	4 3	15	35 35	ns
Q _C	Charge injection	V _{GEN} = 0, R _{GEN} = 0,	C _L = 1 nF	25°C	2.5 V	84			pC
C _{NC(OFF)} , C _{NO(OFF)}	NC, NO OFF capacitance	V _{NC} or V _{NO} = V _{CC} or GND, Switch OFF,	See Figure 19	25°C	2.5 V	52			pF
C _{NC(ON)} , C _{NO(ON)}	NC, NO ON capacitance	V _{NC} or V _{NO} = V _{CC} or GND, Switch OFF,	See Figure 19	25°C	2.5 V	163			pF
C _{COM(ON)}	COM ON capacitance	V _{COM} = V _{CC} or GND,	See Figure 19	25°C	2.5 V	163			pF

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(2) All unused digital inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, [SCBA004](#).

Electrical Characteristics for 2.5-V Supply (continued)

 $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$, $T_A = -40^\circ\text{C to } 85^\circ\text{C}$ (unless otherwise noted)⁽¹⁾

PARAMETER		TEST CONDITIONS	T_A	V_{CC}	MIN	TYP	MAX	UNIT
C_I	Digital input capacitance	$V_I = V_{CC}$ or GND	25°C	2.5 V		2.5		pF
BW	Bandwidth	$R_L = 50 \Omega$, Switch ON	25°C	2.5 V		35		MHz
O_{ISO}	OFF isolation	$R_L = 50 \Omega$, $f = 100 \text{ kHz}$, Switch OFF	25°C	2.5 V		-71		dB
X_{TALK}	Crosstalk	$R_L = 50 \Omega$, $f = 100 \text{ kHz}$, Switch ON	25°C	2.5 V		-73		dB
THD	Total harmonic distortion	$R_L = 600 \Omega$, $C_L = 50 \text{ pF}$, $V_{COM} = \text{GND to } V_{CC}$ $f = 20 \text{ Hz to } 20 \text{ kHz}$	25°C	2.5 V		0.009%		
SUPPLY								
I_{CC}	Positive supply current	$V_I = V_{CC}$ or GND, Switch ON or OFF	25°C Full	2.5 V		0.004	0.1 0.5	μA

6.8 Electrical Characteristics for 3.3-V Supply

 $V_{CC} = 3 \text{ V to } 3.6 \text{ V}$, $T_A = -40^\circ\text{C to } 85^\circ\text{C}$ (unless otherwise noted)⁽¹⁾

PARAMETER		TEST CONDITIONS	T_A	V_{CC}	MIN	TYP	MAX	UNIT
ANALOG SWITCH								
V_{COM} , V_{NO} , V_{NC}	Analog signal range				0		V_{CC}	V
R_{on}	ON-state resistance	V_{NO} or $V_{NC} = 2.0 \text{ V}$, $I_{COM} = -100 \text{ mA}$, Switch ON, See Figure 16	25°C Full	3 V		0.37	0.55 0.6	Ω
ΔR_{on}	ON-state resistance match between channels	V_{NO} or $V_{NC} = 2.0 \text{ V}$, 0.8 V, Switch ON, $I_{COM} = -100 \text{ mA}$, See Figure 16	25°C Full	3 V		0.06	0.07 0.1	Ω
$R_{on(Flat)}$	ON-state resistance flatness	V_{NO} or $V_{NC} = 2.0 \text{ V}$, 0.8 V, Switch ON, $I_{COM} = -100 \text{ mA}$, See Figure 16	25°C Full	3 V		0.05	0.1 0.1	Ω
$I_{NO(OFF)}$, $I_{NC(OFF)}$	NC, NO OFF leakage current	V_{NO} or $V_{NC} = 0.3 \text{ V}$, $V_{COM} = 3.0 \text{ V}$, or V_{NO} or $V_{NC} = 3.0 \text{ V}$, $V_{COM} = 0.3 \text{ V}$, See Figure 17	25°C Full	3.6 V	-15	5	15 50	nA
$I_{NO(ON)}$, $I_{NC(ON)}$	NC, NO ON leakage current	V_{NO} or $V_{NC} = 0.3 \text{ V}$, $V_{COM} = \text{Open}$, or V_{NO} or $V_{NC} = 3.0 \text{ V}$, $V_{COM} = \text{Open}$, See Figure 18	25°C Full	3.6 V	-15	5	15 50	nA
$I_{COM(ON)}$	COM ON leakage current	V_{NO} or $V_{NC} = \text{Open}$, $V_{COM} = 0.3 \text{ V}$, or V_{NO} or $V_{NC} = \text{Open}$, $V_{COM} = 3.0 \text{ V}$, See Figure 18	25°C Full	3.6 V	-15	5	15 50	nA
DIGITAL CONTROL INPUTS (IN1-2, IN3-4)⁽²⁾								
V_{IH}	Input logic high		Full		1.25		4.3	V
V_{IL}	Input logic low		Full		0		0.8	V
I_{IH} , I_{IL}	Input leakage current	$V_{IN} = 3.6 \text{ V or } 0$	25°C Full	3.6 V		0.5	10 50	nA

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(2) All unused digital inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, [SCBA004](#).

Electrical Characteristics for 3.3-V Supply (continued)

 $V_{CC} = 3\text{ V to }3.6\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)⁽¹⁾

PARAMETER		TEST CONDITIONS		T _A	V _{CC}	MIN	TYP	MAX	UNIT
DYNAMIC									
t _{ON}	Turn-on time	V _{COM} = V _{CC} , R _L = 50 Ω, C _L = 35 pF	25°C	3 V	20	38	ns		
			Full	3 V to 3.6 V		40			
t _{OFF}	Turn-off time	V _{COM} = V _{CC} , R _L = 50 Ω, C _L = 35 pF	25°C	3 V	14	34	ns		
			Full	3 V to 3.6 V		35			
t _{BBM}	Break-before-make time	V _{NC} = V _{NO} = V _{CC} , R _L = 50 Ω, C _L = 35 pF	25°C	3 V	3	11	35	ns	
			Full	3 V to 3.6 V	2		55		
Q _C	Charge injection	V _{GEN} = 0, R _{GEN} = 0, C _L = 1 nF	25°C	3 V	109			pC	
C _{NC(OFF)} , C _{NO(OFF)}	NC, NO OFF capacitance	V _{NC} or V _{NO} = V _{CC} or GND, Switch OFF, See Figure 19	25°C	3 V	51			pF	
C _{NC(ON)} , C _{NO(ON)}	NC, NO ON capacitance	V _{NC} or V _{NO} = V _{CC} or GND, Switch OFF, See Figure 19	25°C	3 V	162			pF	
C _{COM(ON)}	COM ON capacitance	V _{COM} = V _{CC} or GND, Switch ON, See Figure 19	25°C	3 V	162			pF	
C _I	Digital input capacitance	V _I = V _{CC} or GND	25°C	3 V	2.5			pF	
BW	Bandwidth	R _L = 50 Ω, Switch ON	25°C	3 V	35			MHz	
O _{ISO}	OFF isolation	R _L = 50 Ω, f = 100 kHz, Switch OFF	25°C	3 V	−71			dB	
X _{TALK}	Crosstalk	R _L = 50 Ω, f = 100 kHz, Switch ON	25°C	3 V	−73			dB	
THD	Total harmonic distortion	R _L = 600 Ω, C _L = 50 pF, V _{COM} = GND to V _{CC} f = 20 Hz to 20 kHz	25°C	3 V	0.003%				
SUPPLY									
I _{CC}	Positive supply current	V _I = V _{CC} or GND, Switch ON or OFF	25°C	3.6 V	0.015	0.2	μA		
			Full			0.7			

6.9 Electrical Characteristics for 4.3-V Supply

 $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)⁽¹⁾

PARAMETER		TEST CONDITIONS		T _A	V _{CC}	MIN	TYP	MAX	UNIT
ANALOG SWITCH									
V _{COM} , V _{NO} , V _{NC}	Analog signal range					0		V _{CC}	V
R _{on}	ON-state resistance	V _{NO} or V _{NC} = 2.5 V, I _{COM} = −100 mA,	Switch ON, See Figure 16	25°C	4.3 V	0.3	0.45		Ω
				Full		0.5			
ΔR _{on}	ON-state resistance match between channels	V _{NO} or V _{NC} = 2.5 V, I _{COM} = −100 mA,	Switch ON, See Figure 16	25°C	4.3 V	0.05	0.07		Ω
				Full		0.1			
R _{on(flat)}	ON-state resistance flatness	V _{NO} or V _{NC} = 1 V, 1.5 V, 2.5 V, I _{COM} = −100 mA,	Switch ON, See Figure 16	25°C	4.3 V	0.02	0.1		Ω
				Full		0.1			

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

Electrical Characteristics for 4.3-V Supply (continued)

 $T_A = -40^{\circ}\text{C}$ to 85°C (unless otherwise noted)⁽¹⁾

PARAMETER		TEST CONDITIONS		T _A	V _{CC}	MIN	TYP	MAX	UNIT
I _{NO(OFF)} , I _{NC(OFF)}	NC, NO OFF leakage current	V _{NO} or V _{NC} = 0.3 V, V _{COM} = 3.0 V, or V _{NO} or V _{NC} = 3.0 V, V _{COM} = 0.3 V,	See Figure 17	25°C	4.3 V	−20	5	20	nA
				Full		−90		90	
I _{NO(ON)} , I _{NC(ON)}	NC, NO ON leakage current	V _{NO} or V _{NC} = 0.3 V, V _{COM} = Open, or V _{NO} or V _{NC} = 3.0 V, V _{COM} = Open,	See Figure 18	25°C	4.3 V	−20	5	20	nA
				Full		−90		90	
I _{COM(ON)}	COM ON leakage current	V _{NO} or V _{NC} = Open, V _{COM} = 0.3 V, or V _{NO} or V _{NC} = Open, V _{COM} = 3.0 V,	See Figure 18	25°C	4.3 V	−20	5	20	nA
				Full		−90		90	
DIGITAL CONTROL INPUTS (IN1-2, IN3-4) ⁽²⁾									
V _{IH}	Input logic high			Full	4.3 V	1.5		4.3	V
V _{IL}	Input logic low			Full	4.3 V	0		1	V
I _{IH} , I _{IL}	Input leakage current	V _{IN} = 3.6 V or 0		25°C	4.3 V		0.5	10	nA
				Full				50	
DYNAMIC									
t _{ON}	Turn-on time	V _{COM} = V _{CC} , R _L = 50 Ω,	C _L = 35 pF	25°C	4.3 V		17	23	ns
				Full				25	
t _{OFF}	Turn-off time	V _{COM} = V _{CC} , R _L = 50 Ω,	C _L = 35 pF	25°C	4.3 V		12	32	ns
				Full				35	
t _{BBM}	Break-before-make time	V _{NC} = V _{NO} = V _{CC} , R _L = 50 Ω,	C _L = 35 pF	25°C	4.3 V	2	9	30	ns
				Full		1		35	
Q _C	Charge injection	V _{GEN} = 0, R _{GEN} = 0,	C _L = 1 nF	25°C	4.3 V		139		pC
C _{NC(OFF)} , C _{NO(OFF)}	NC, NO off capacitance	V _{NC} or V _{NO} = V _{CC} or GND, Switch OFF,	See Figure 19	25°C	4.3 V		50		pF
C _{NC(ON)} , C _{NO(ON)}	NC, NO ON capacitance	V _{NC} or V _{NO} = V _{CC} or GND, Switch OFF,	See Figure 19	25°C	4.3 V		160		pF
C _{COM(ON)}	COM ON capacitance	V _{COM} = V _{CC} or GND, Switch ON,	See Figure 19	25°C	4.3 V		160		pF
C _I	Digital input capacitance	V _I = V _{CC} or GND		25°C	4.3 V		2.5		pF
BW	Bandwidth	R _L = 50 Ω, Switch ON		25°C	4.3 V		35		MHz
O _{ISO}	OFF isolation	R _L = 50 Ω, f = 100 kHz, Switch OFF		25°C	4.3 V		−71		dB
X _{TALK}	Crosstalk	R _L = 50 Ω, f = 100 kHz, Switch ON		25°C	4.3 V		−73		dB
THD	Total harmonic distortion	R _L = 600 Ω, C _L = 50 pF, V _{COM} = GND to V _{CC} f = 20 Hz to 20 kHz		25°C	4.3 V		0.003%		
SUPPLY									
I _{CC}	Positive supply current	V _I = V _{CC} or GND, Switch ON or OFF		25°C	4.3 V		0.15	0.4	μA
				Full				1.2	

(2) All unused digital inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, [SCBA004](#).

6.10 Typical Characteristics

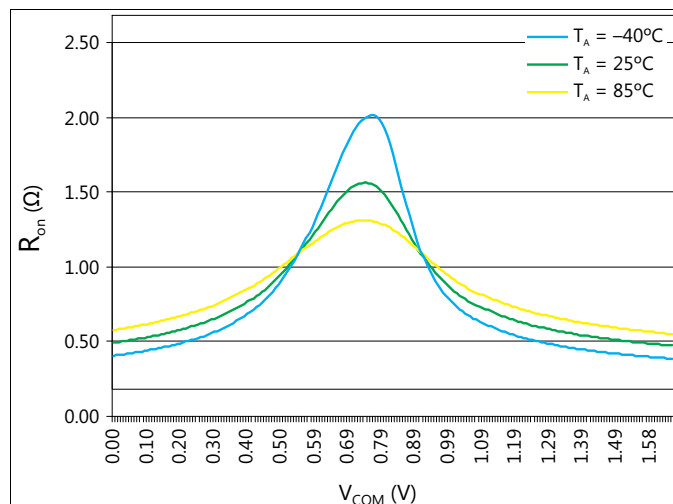


Figure 1. R_{on} vs V_{COM} ($V_{CC} = 1.65$ V)

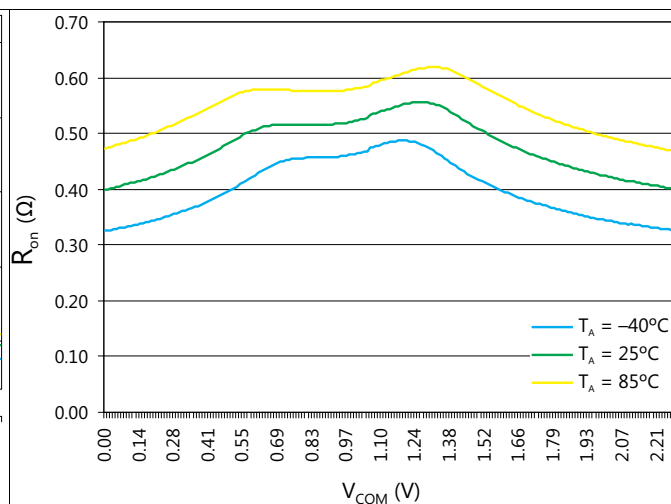


Figure 2. R_{on} vs V_{COM} ($V_{CC} = 2.3$ V)

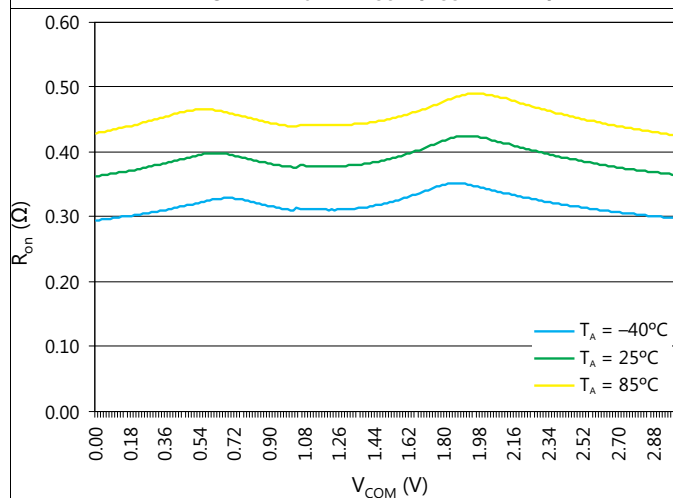


Figure 3. R_{on} vs V_{COM} ($V_{CC} = 3$ V)

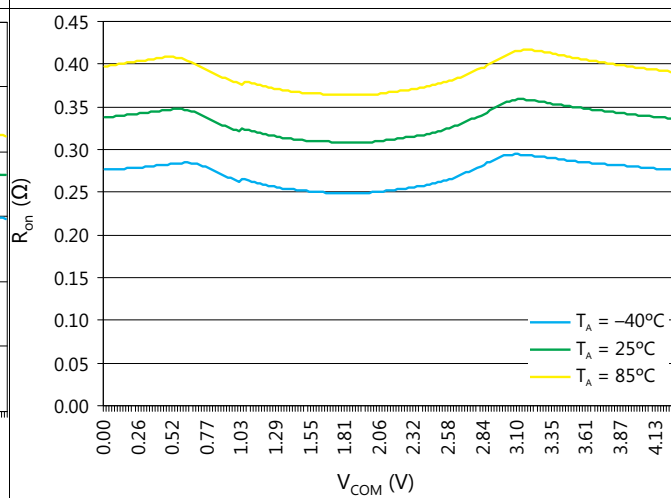


Figure 4. R_{on} vs V_{COM} ($V_{CC} = 4.3$ V)

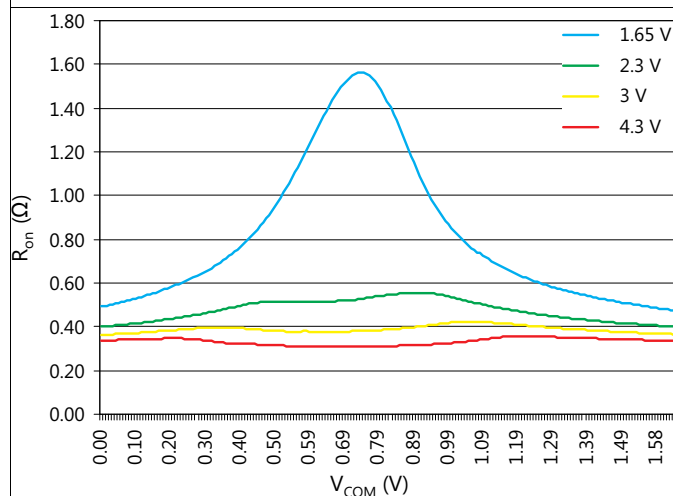


Figure 5. R_{on} vs V_{COM} (All Voltages)

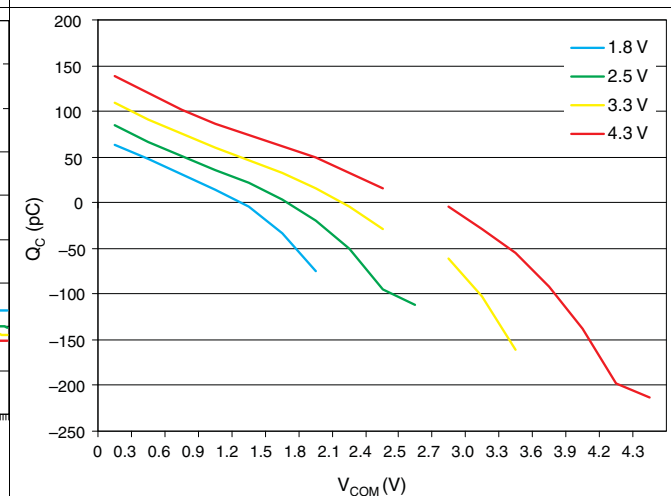


Figure 6. Charge Injection (Q_C) vs V_{COM} ($T_A = 25^\circ\text{C}$)

Typical Characteristics (continued)

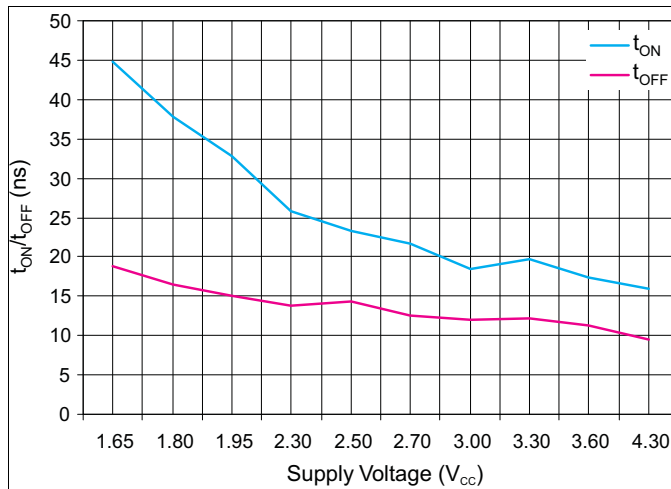


Figure 7. t_{ON} and t_{OFF} vs Supply Voltage (T_A = 25°C)

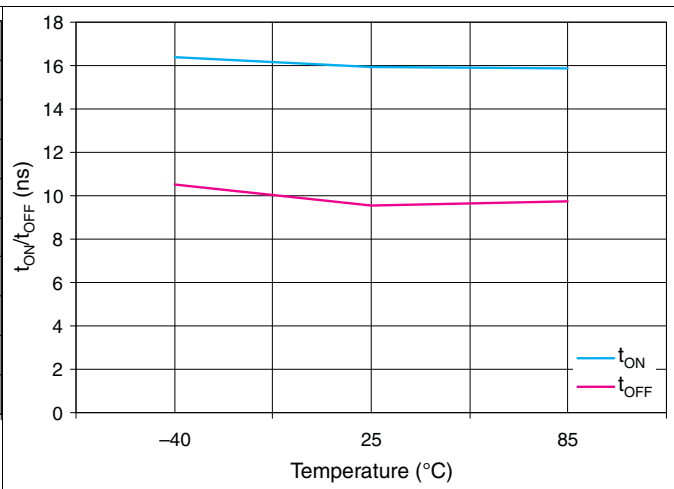


Figure 8. t_{ON} and t_{OFF} vs Temperature (V_{CC} = 4.3 V)

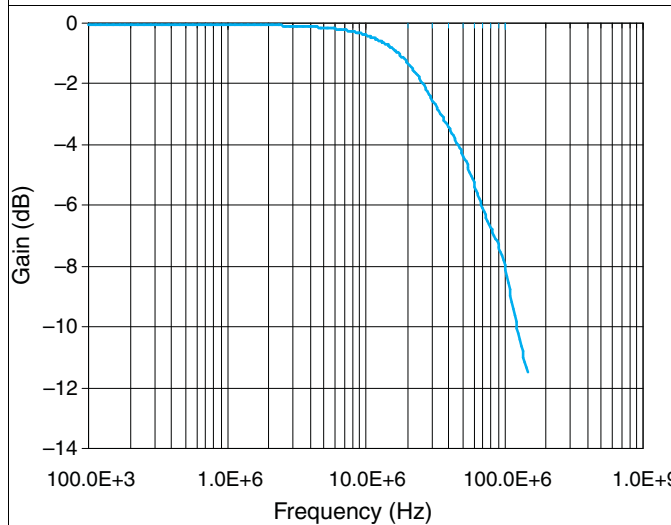


Figure 9. Bandwidth

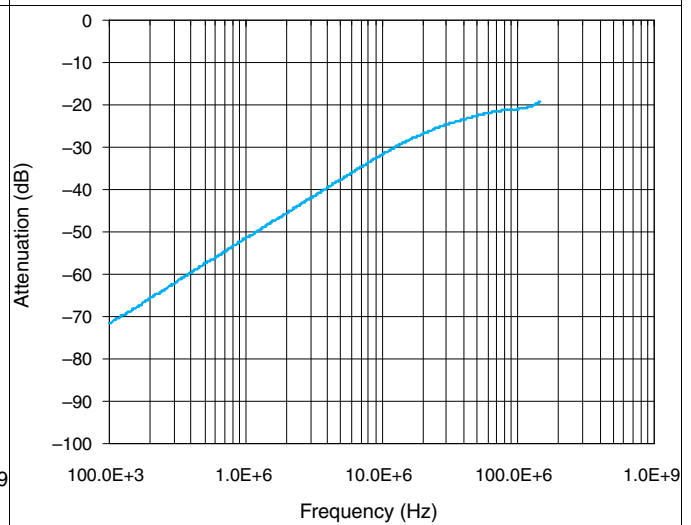


Figure 10. OFF Isolation

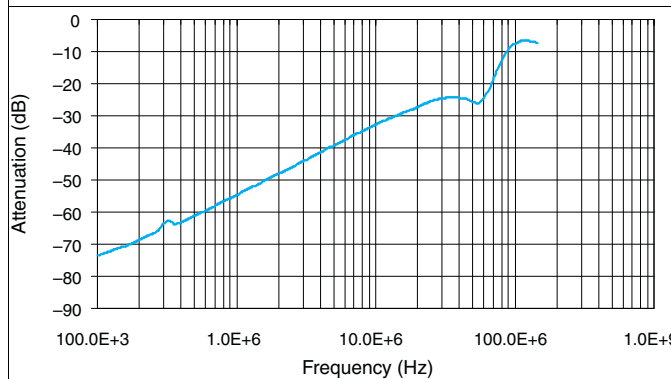


Figure 11. Crosstalk

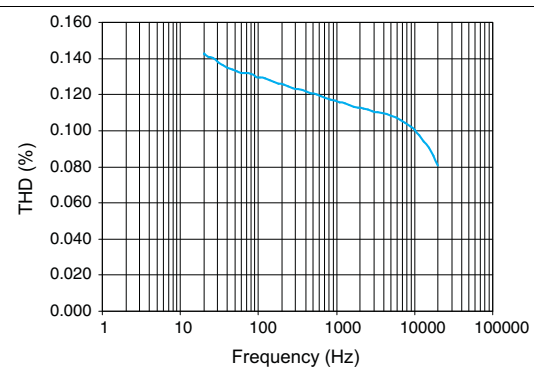


Figure 12. Total Harmonic Distortion vs Frequency (V_{CC} = 1.8 V)

Typical Characteristics (continued)

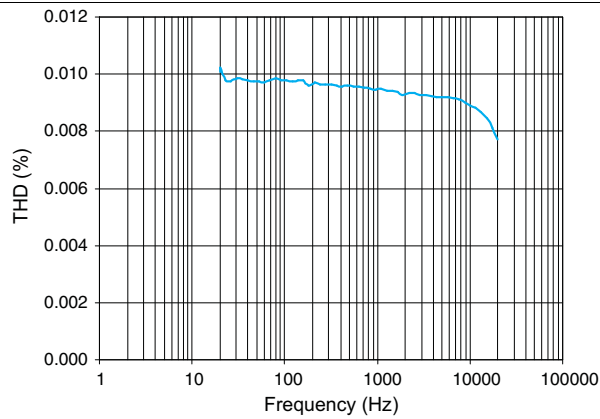


Figure 13. Total Harmonic Distortion vs Frequency
($V_{CC} = 2.5\text{ V}$)

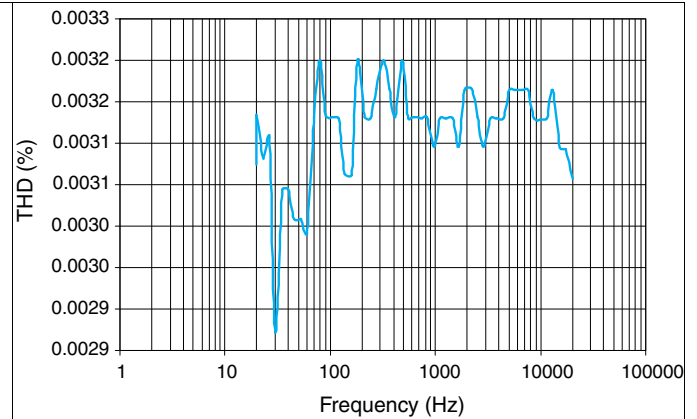


Figure 14. Total Harmonic Distortion vs Frequency
($V_{CC} = 3.3\text{ V}$)

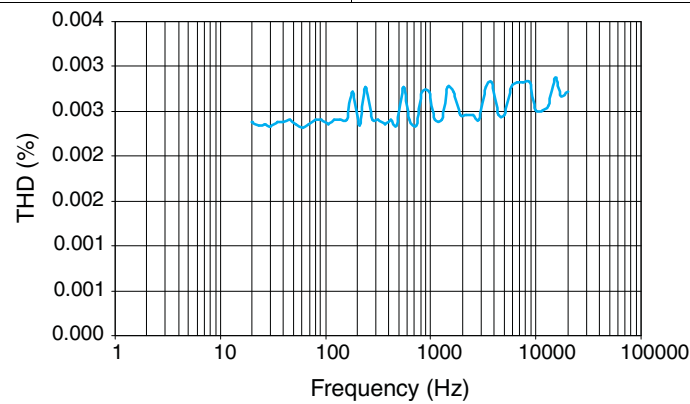


Figure 15. Total Harmonic Distortion vs Frequency ($V_{CC} = 4.3\text{ V}$)

7 Parameter Measurement Information

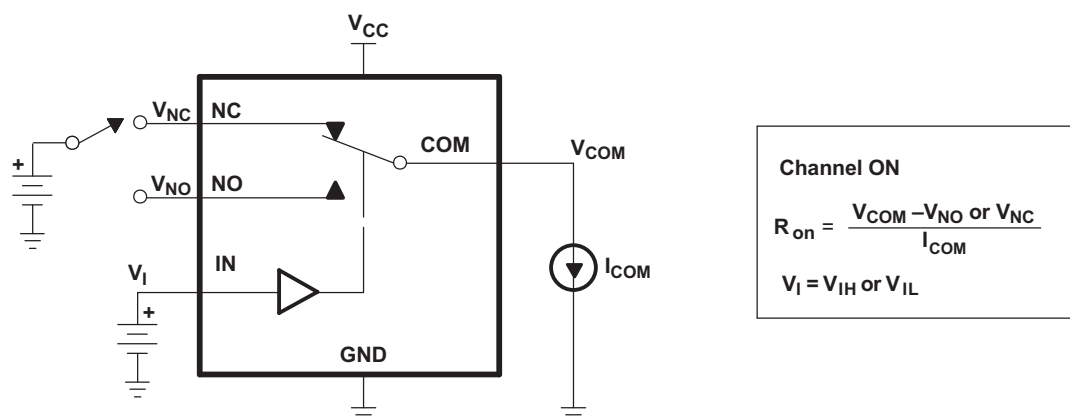


Figure 16. ON-state Resistance (R_{ON})

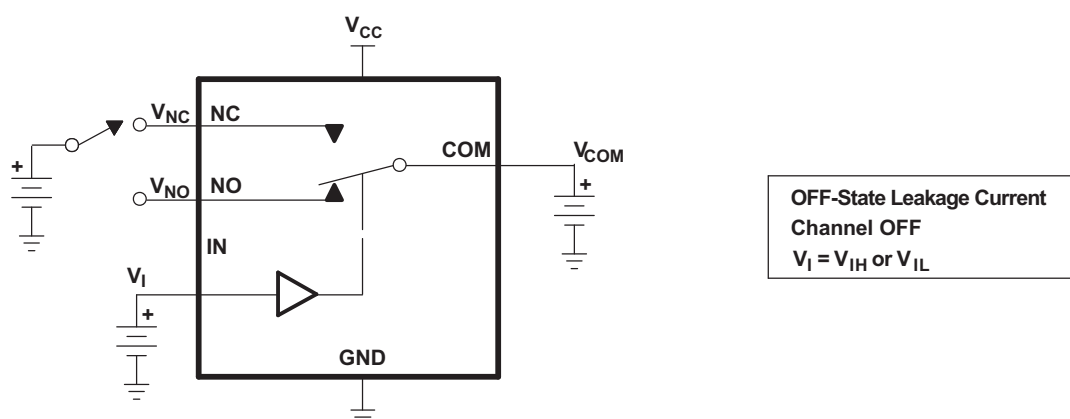


Figure 17. OFF-State Leakage Current ($I_{NC(OFF)}$, $I_{NC(PWROFF)}$, $I_{NO(OFF)}$, $I_{NO(PWROFF)}$, $I_{COM(OFF)}$, $I_{COM(PWROFF)}$)

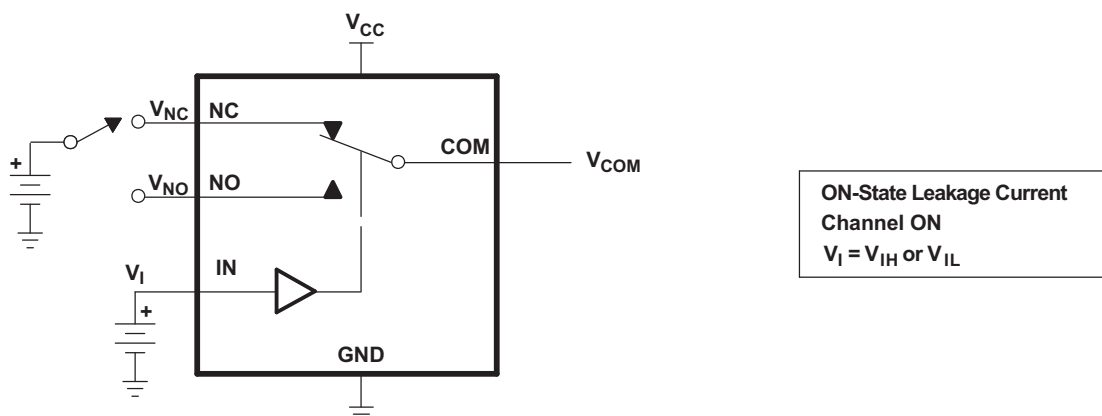


Figure 18. ON-State Leakage Current ($I_{COM(ON)}$, $I_{NC(ON)}$, $I_{NO(ON)}$)

Parameter Measurement Information (continued)

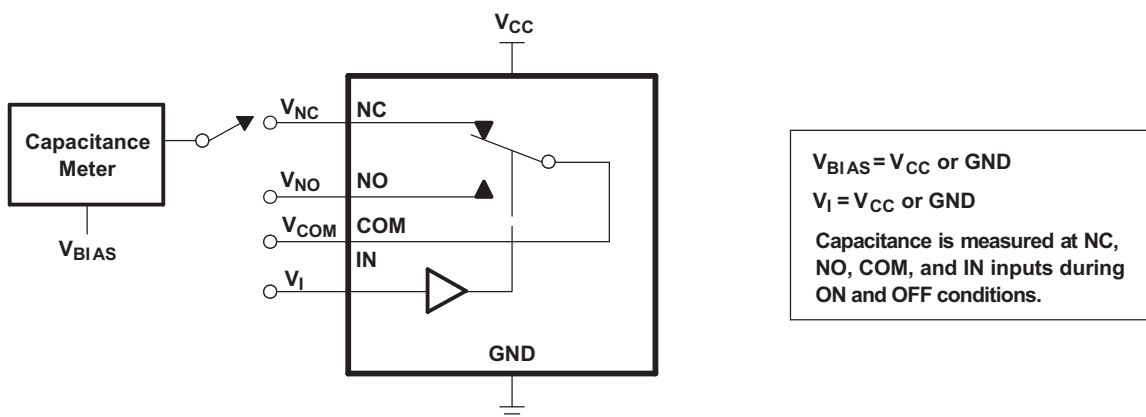
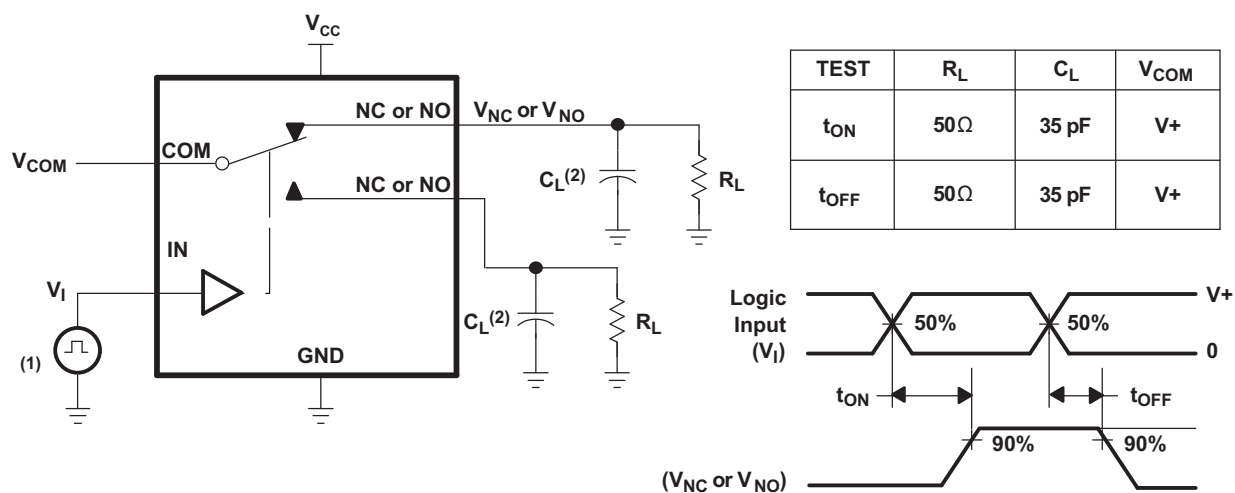


Figure 19. Capacitance (C_I , $C_{COM(ON)}$, $C_{NC(OFF)}$, $C_{NO(OFF)}$, $C_{NC(ON)}$, $C_{NO(ON)}$)



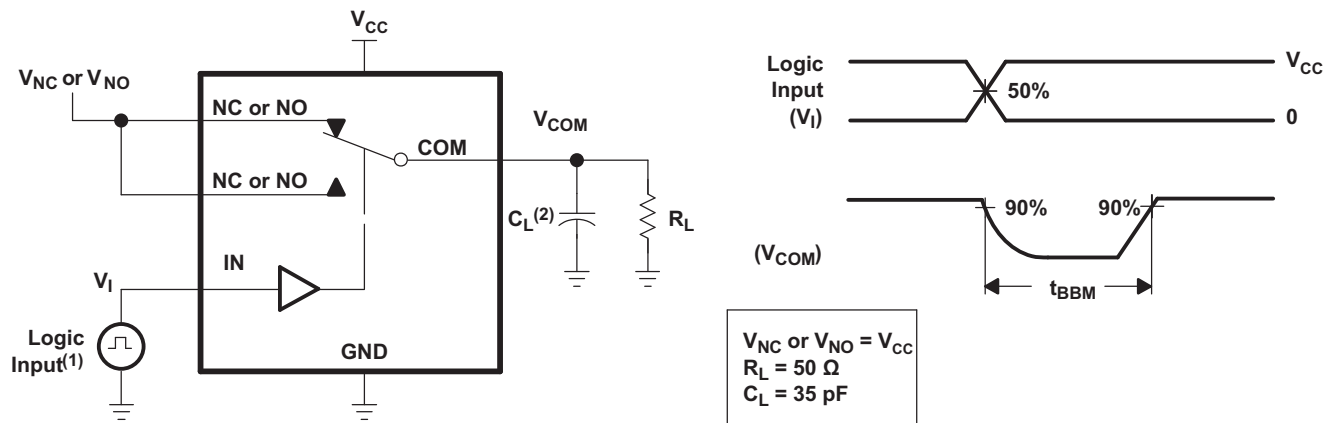
A. All input pulses are supplied by generators having the following characteristics:

PRR ≤ 10 MHz, Z_O = 50 Ω, t_r < 5 ns, t_f < 5 ns.

B. C_L includes probe and jig capacitance.

Figure 20. Turn-On (t_{ON}) and Turn-Off Time (t_{OFF})

Parameter Measurement Information (continued)



A. C_L includes probe and jig capacitance.

B. All input pulses are supplied by generators having the following characteristics:

PRR $\leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r < 5 \text{ ns}$, $t_f < 5 \text{ ns}$.

Figure 21. Break-Before-Make Time (t_{BBM})

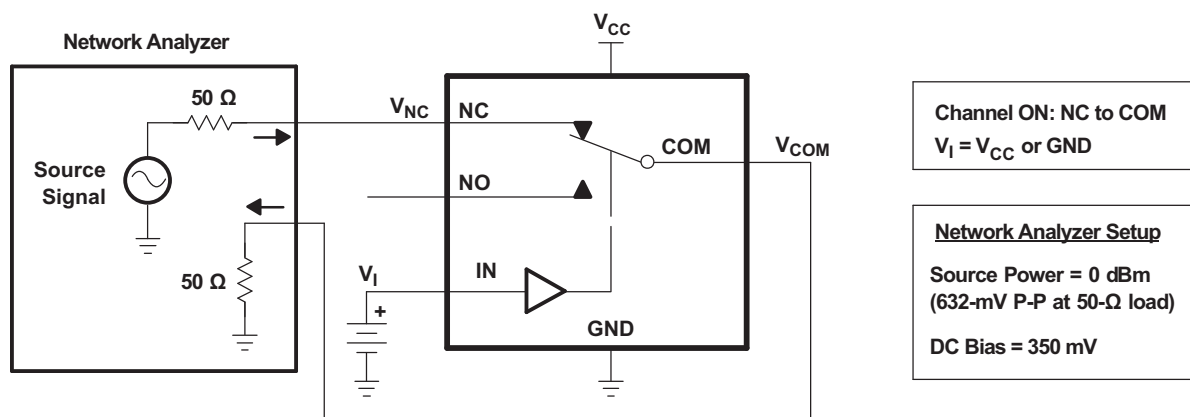


Figure 22. Bandwidth (BW)

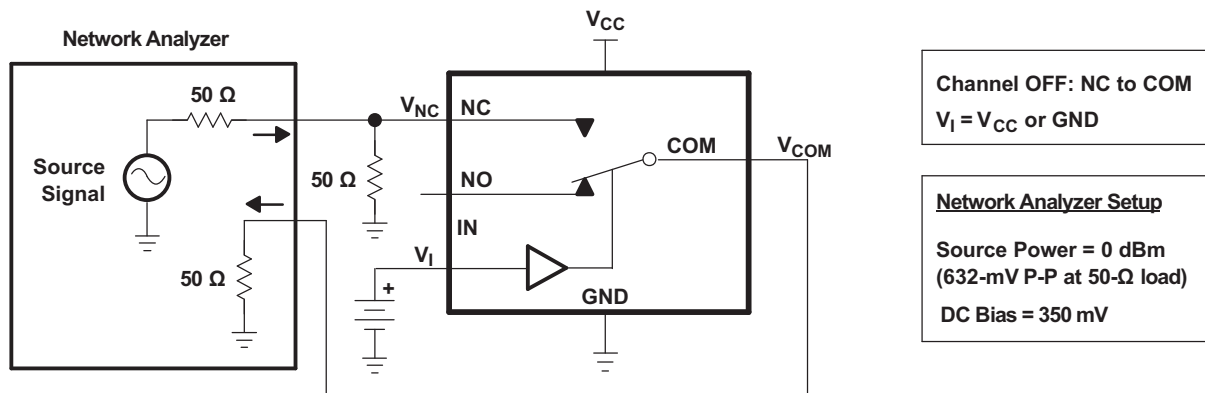


Figure 23. OFF Isolation (O_{ISO})

Parameter Measurement Information (continued)

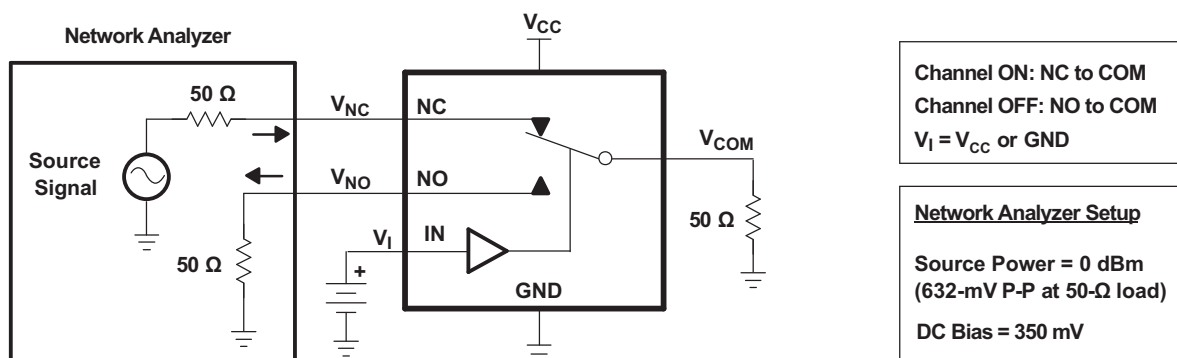
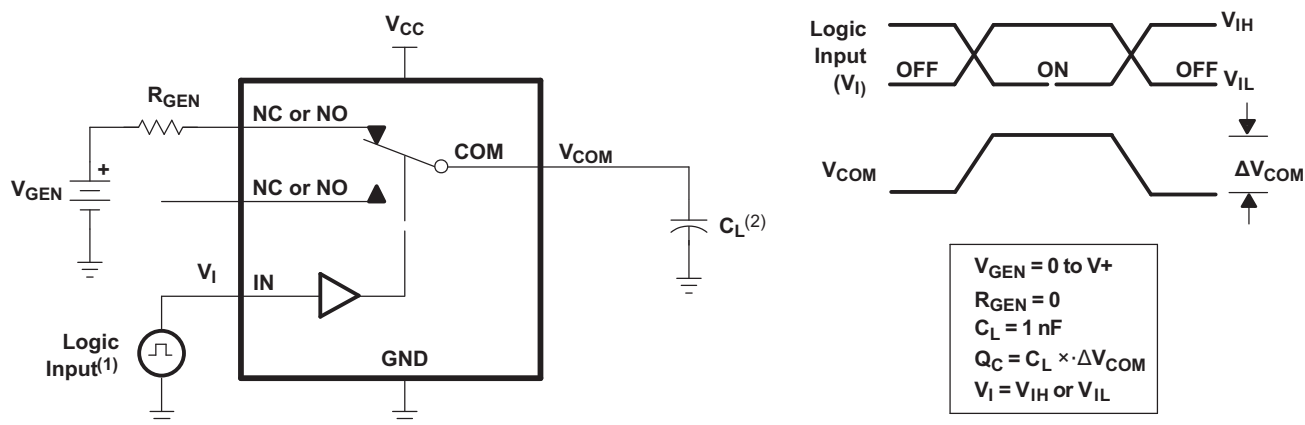


Figure 24. Crosstalk (X_{TALK})



A. All input pulses are supplied by generators having the following characteristics:

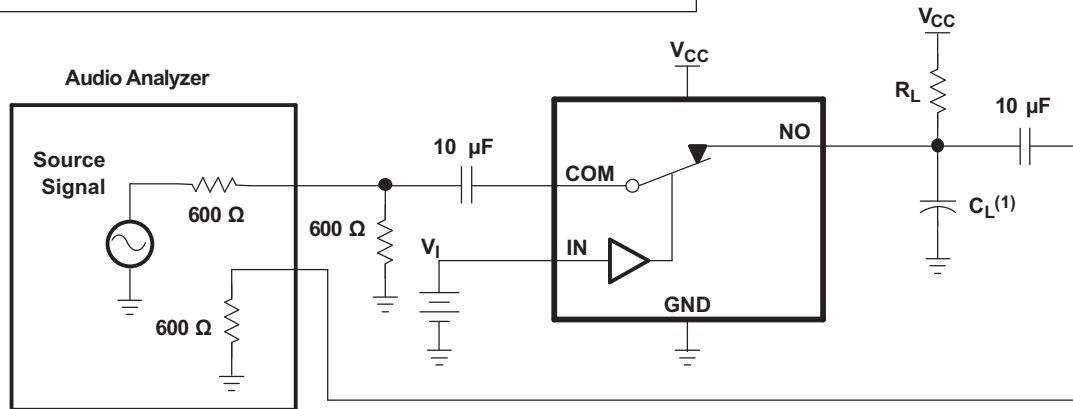
PRR $\leq$ 10 MHz, $Z_O = 50 \Omega$, $t_r < 5$ ns, $t_f < 5$ ns.

B. C_L includes probe and jig capacitance.

Figure 25. Charge Injection (Q_C)

Parameter Measurement Information (continued)

Channel ON: COM to NO	$V_I = V_{IH}$ or V_{IL}	$R_L = 600$
$V_{SOURCE} = GND$ to V_{CC}	Source Signal = 20 Hz to 20 kHz	$C_L = 50$ pF



A. C_L includes probe and jig capacitance.

Figure 26. Total Harmonic Distortion (THD)

8 Detailed Description

8.1 Overview

The TS3A44159 is a bidirectional 4-channel single-pole double-throw (SPDT) analog switch with two control inputs, which is designed to operate from 1.65 V to 4.3 V. This device is also known as a 2-channel, double-pole, double-throw (DPDT) configuration. It offers low ON-state resistance and excellent ON-state resistance matching with the break-before-make feature that prevents signal distortion during the transferring of a signal from one channel to another. The device has an excellent total harmonic distortion (THD) performance and consumes very low power. These features make this device suitable for portable audio applications.

8.2 Functional Block Diagram

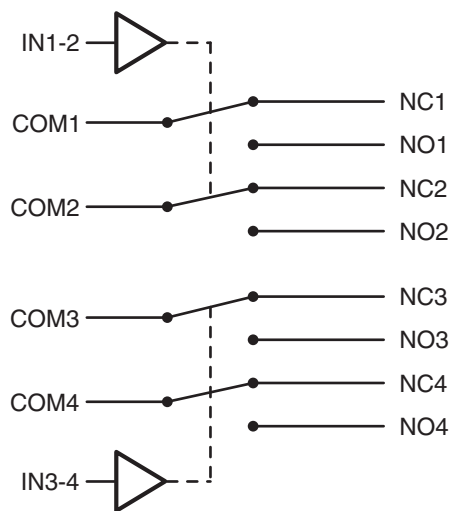


Figure 27. Logic Diagram

8.3 Feature Description

The TS3A44159 is a bidirectional device that has two sets of two single-pole double-throw switches. The four channels of the switch are controlled by two digital signals; one digital control for each set of two single-pole double-throw switches.

8.4 Device Functional Modes

Table 1. Function Table

IN	NC TO COM, COM TO NC	NO TO COM, COM TO NO
L	ON	OFF
H	OFF	ON

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The switches are bidirectional, so the NO, NC, and COM pins can be used as either inputs or outputs.

9.2 Typical Application

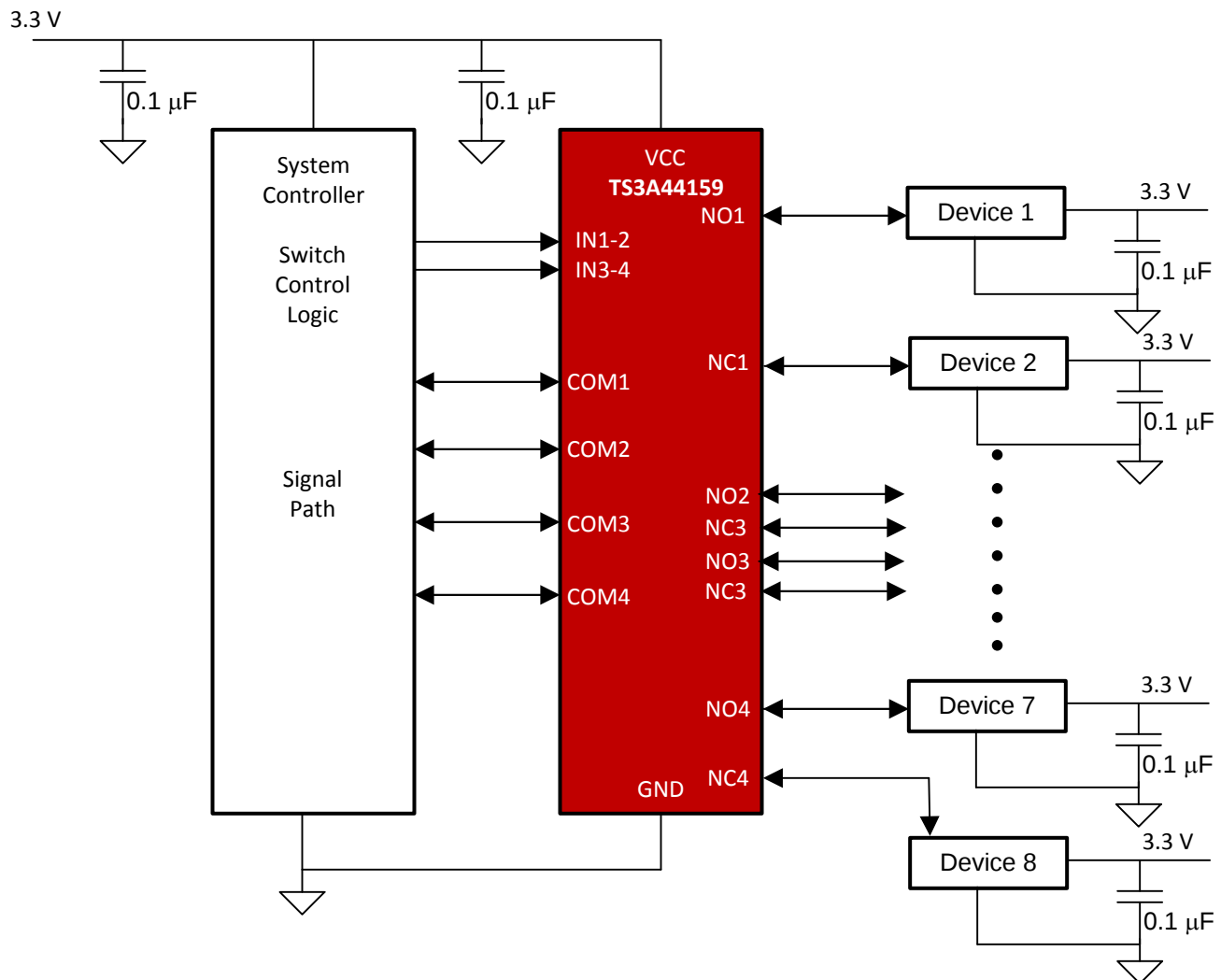


Figure 28. Typical Application Diagram

9.2.1 Design Requirements

Ensure that all of the signals passing through the switch are within the specified ranges to ensure proper performance.

Table 2. Design Parameters

DESIGN PARAMETERS	EXAMPLE VALUES
Analog Voltage	4.3 V
Digital Input Voltage	4.3 V

9.2.2 Detailed Design Procedure

The TS3A44159 can be properly operated without any external components. However, TI recommends to connect unused pins to the ground through a 50-Ω resistor to prevent signal reflections back into the device. TI also recommends that the digital control pins (INX) be pulled up to VCC or down to GND to avoid undesired switch positions that could result from the floating pin.

9.2.3 Application Curve

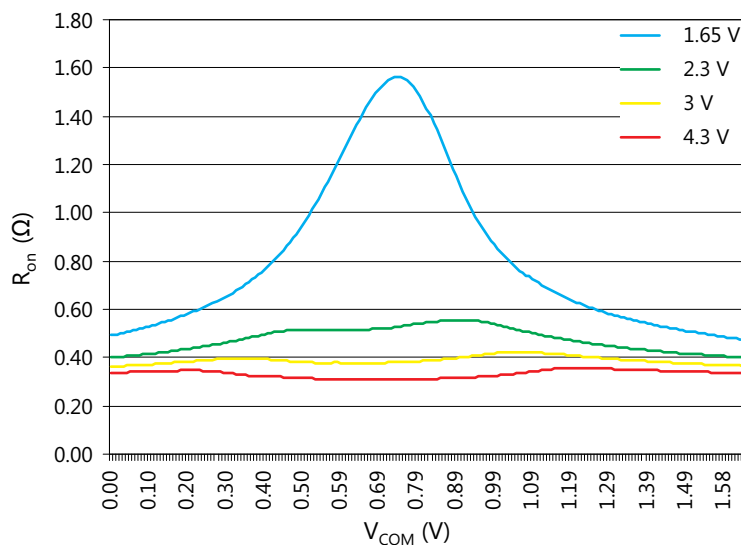


Figure 29. R_{on} vs V_{COM} (All Voltages)

10 Power Supply Recommendations

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the device. Always sequence V_{CC} on first, followed by NO, NC, or COM. Although it is not required, power-supply bypassing improves noise margin and prevents switching noise propagation from the V_{CC} supply to other components. A 0.1- μ F capacitor, connected from V_{CC} to GND, is adequate for most applications.

11 Layout

11.1 Layout Guidelines

High-speed switches require proper layout and design procedures for optimum performance. Reduce stray inductance and capacitance by keeping traces short and wide. Ensure that bypass capacitors are as close to the device as possible. Use large ground planes where possible.

11.2 Layout Example

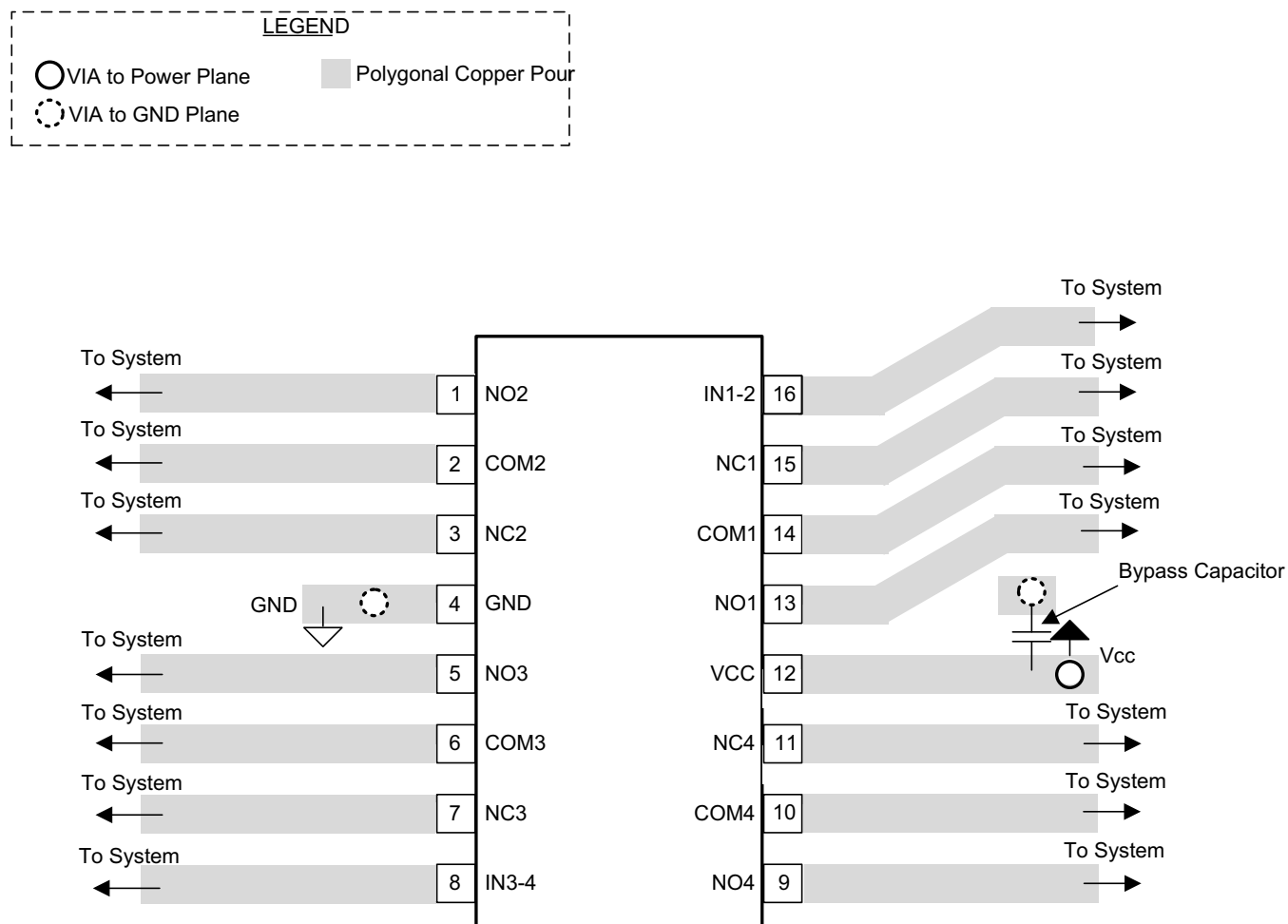


Figure 30. PCB Layout Example

12 Device and Documentation Support

12.1 Trademarks

All trademarks are the property of their respective owners.

12.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.3 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TS3A44159PWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YC4159
TS3A44159PWR.A	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YC4159
TS3A44159PWRG4	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YC4159
TS3A44159RGTR	Active	Production	VQFN (RGT) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZWH
TS3A44159RGTR.A	Active	Production	VQFN (RGT) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZWH
TS3A44159RGTRG4	Active	Production	VQFN (RGT) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZWH
TS3A44159RSVR	Active	Production	UQFN (RSV) 16	3000 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	ZWH
TS3A44159RSVR.A	Active	Production	UQFN (RSV) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZWH
TS3A44159RSVRG4	Active	Production	UQFN (RSV) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZWH

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative

and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS3A44159PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TS3A44159RGTR	VQFN	RGT	16	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

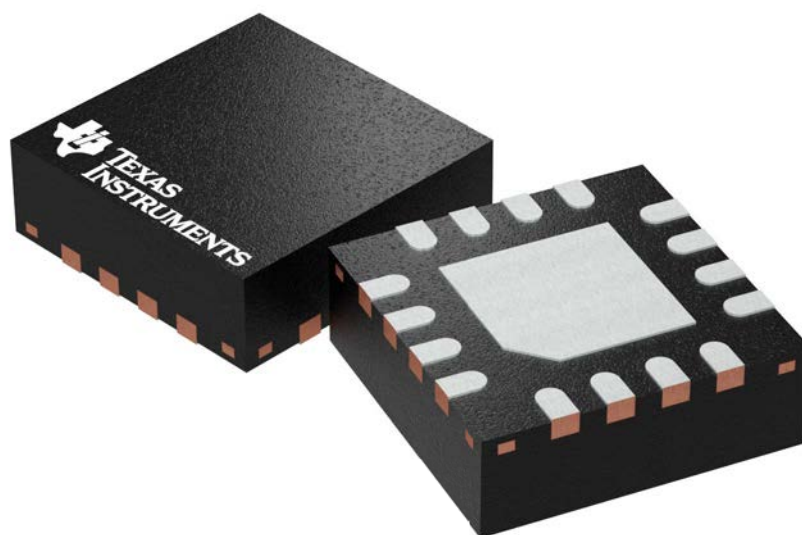
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS3A44159PWR	TSSOP	PW	16	2000	353.0	353.0	32.0
TS3A44159RGTR	VQFN	RGT	16	3000	346.0	346.0	35.0

RGT 16

GENERIC PACKAGE VIEW

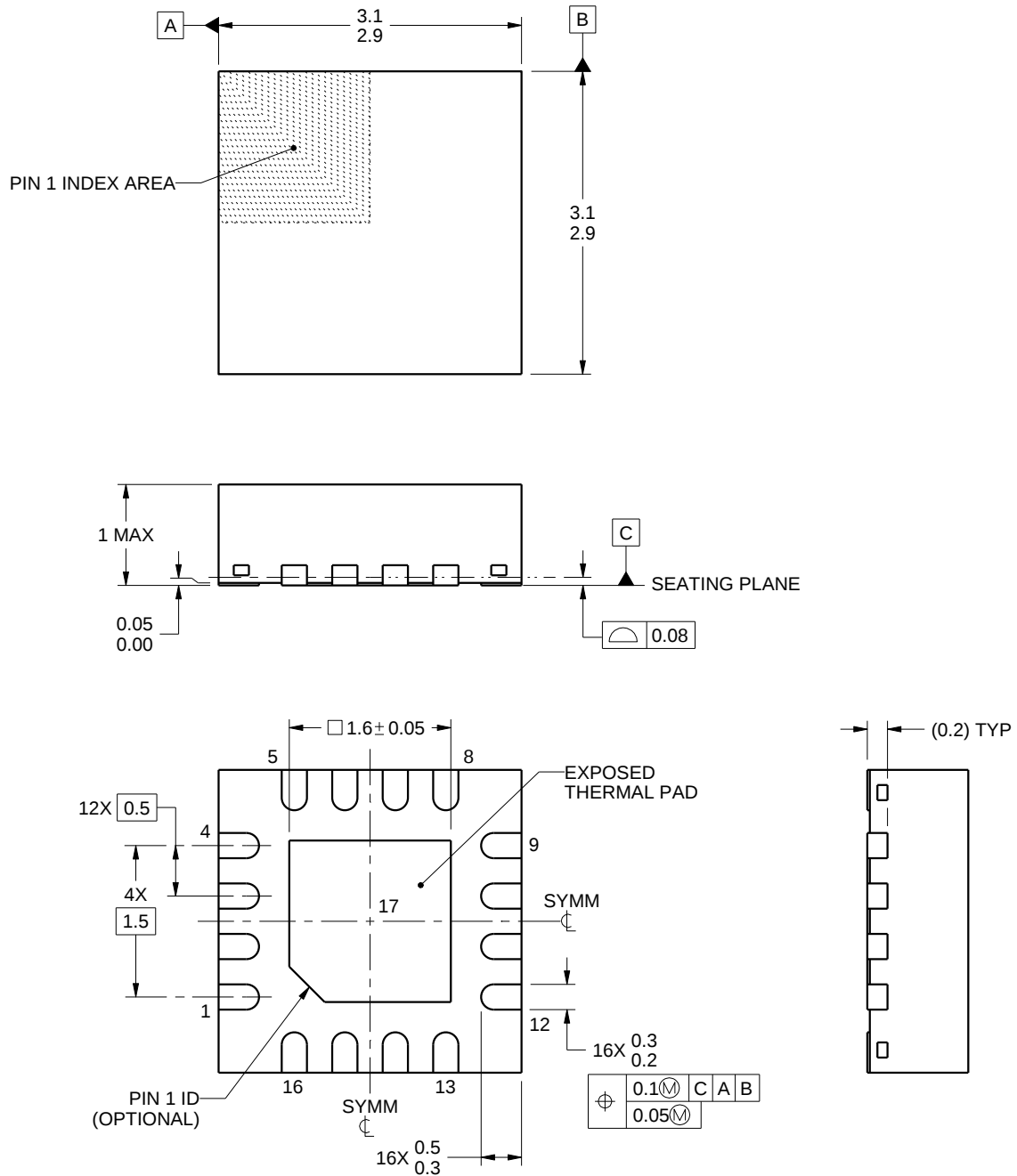
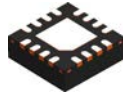
VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

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4219033/A 08/2016

NOTES:

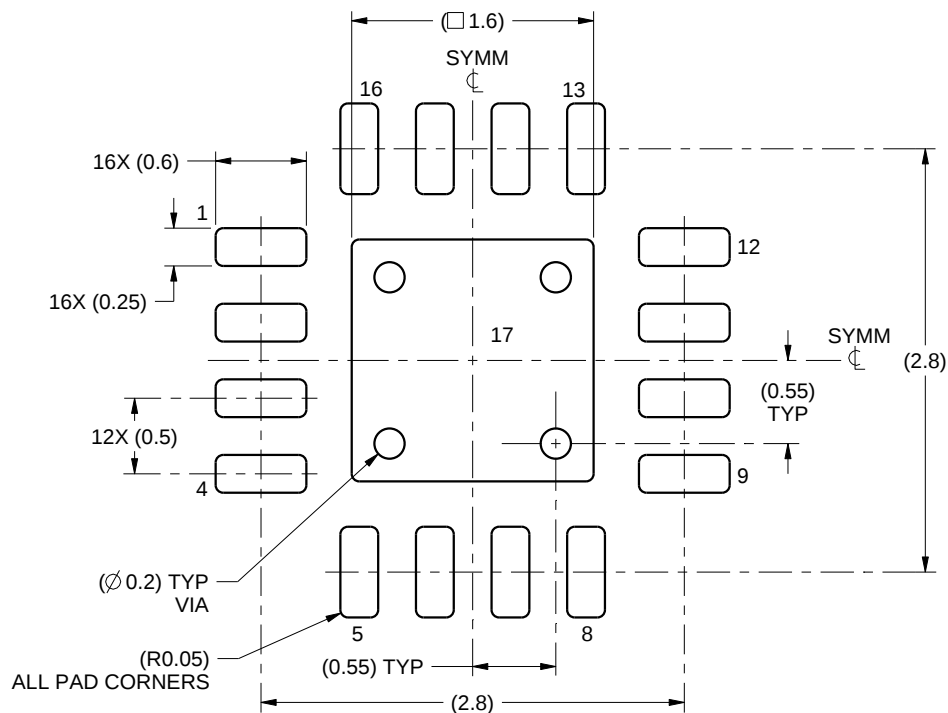
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

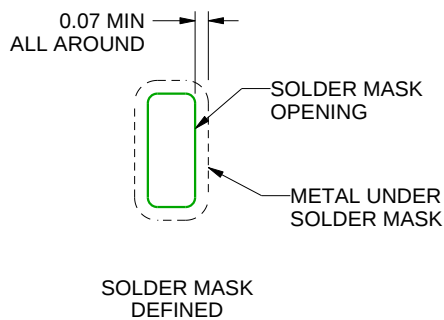
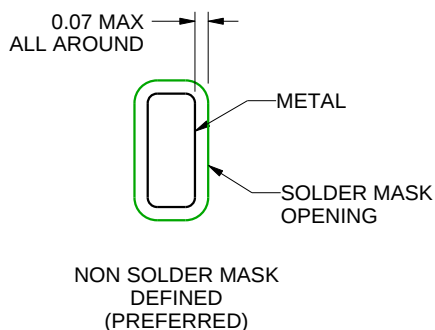
RGT0016B

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
SCALE:20X



SOLDER MASK DETAILS

4219033/A 08/2016

NOTES: (continued)

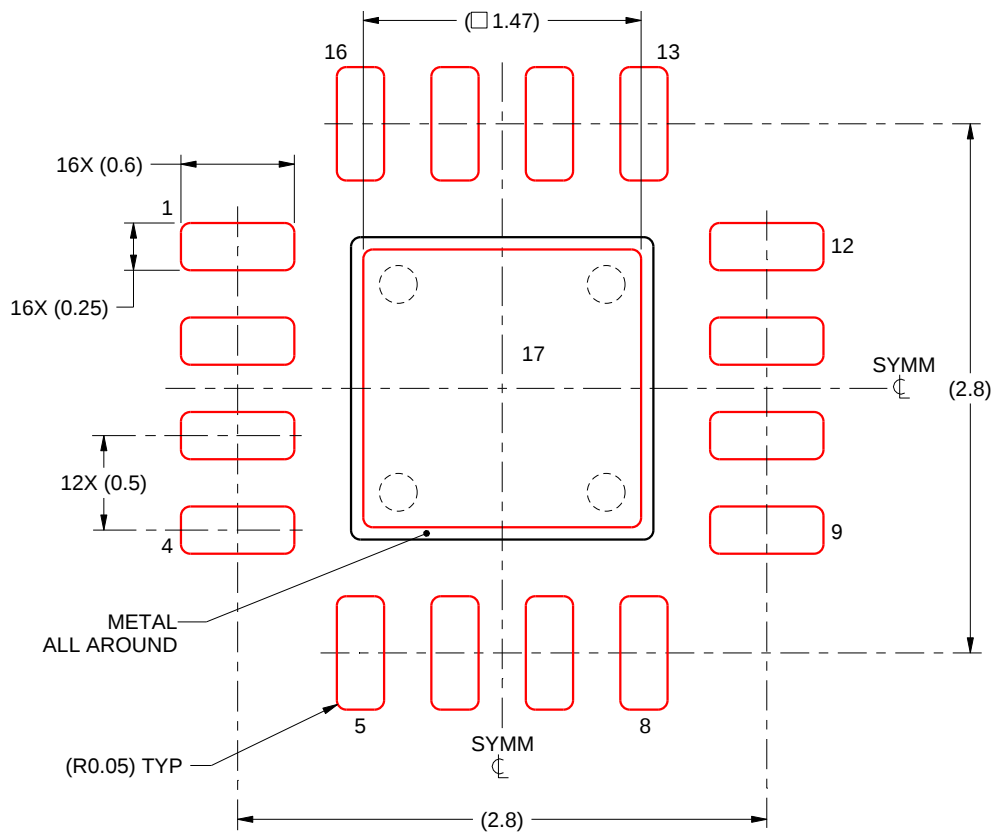
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RGT0016B

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 17:
84% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:25X

4219033/A 08/2016

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

GENERIC PACKAGE VIEW

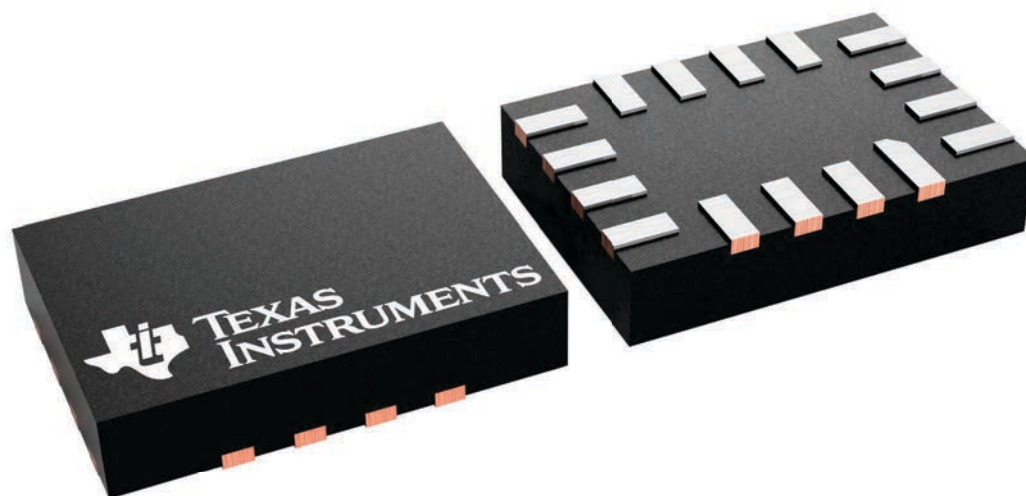
RSV 16

UQFN - 0.55 mm max height

1.8 x 2.6, 0.4 mm pitch

ULTRA THIN QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



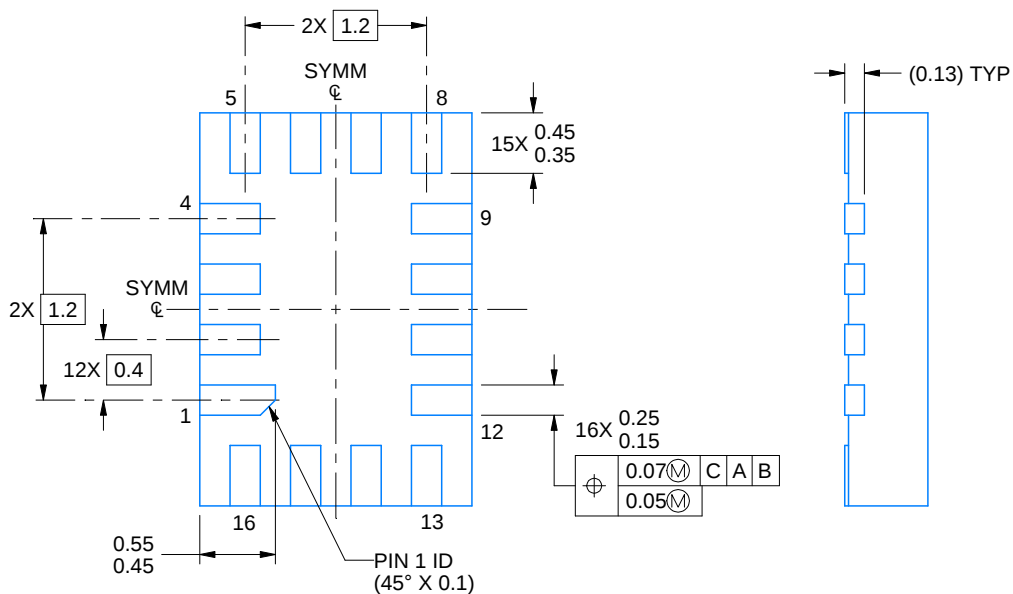
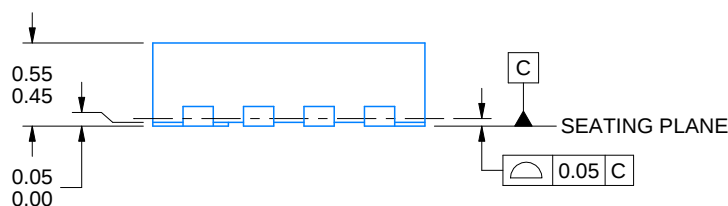
UQFN - 0.55 mm max height

Diagram illustrating a PCB layout with dimensions and a PIN 1 INDEX AREA.

Dimensions:

- Horizontal distance between points B and A: 1.85 (total) and 1.75 (from B to the start of the index area).
- Vertical distance from the top edge to the bottom edge: 2.65 (total) and 2.55 (from the start of the index area to the bottom edge).

The PIN 1 INDEX AREA is indicated by a line pointing to a specific location within the layout.



NOTES:

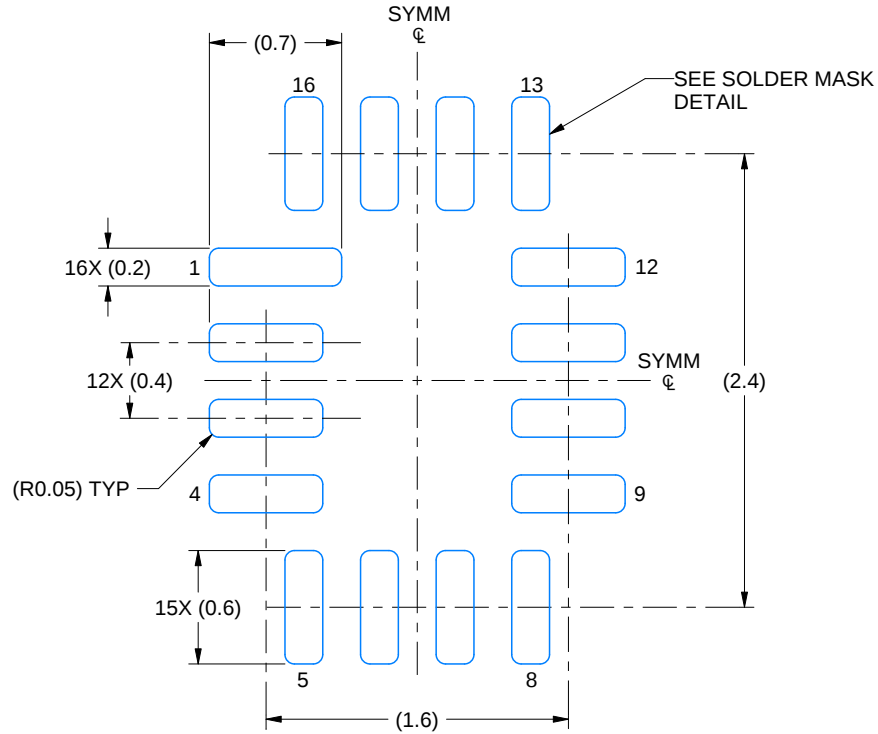
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

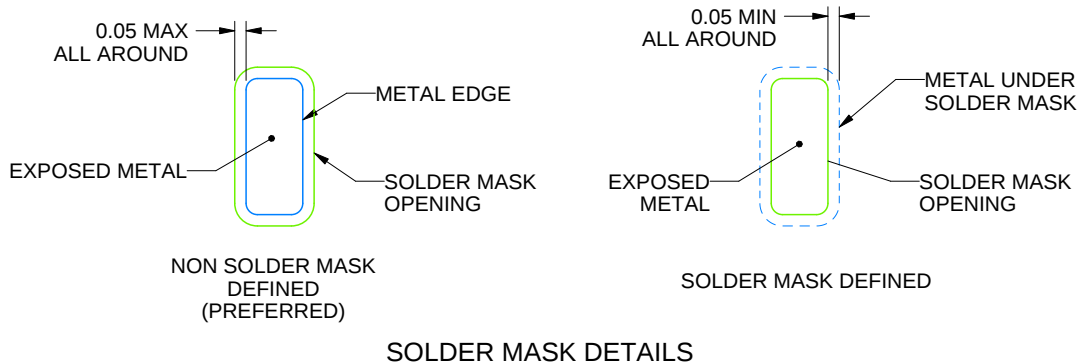
RSV0016A

UQFN - 0.55 mm max height

ULTRA THIN QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 25X



SOLDER MASK DETAILS

4220314/C 02/2020

NOTES: (continued)

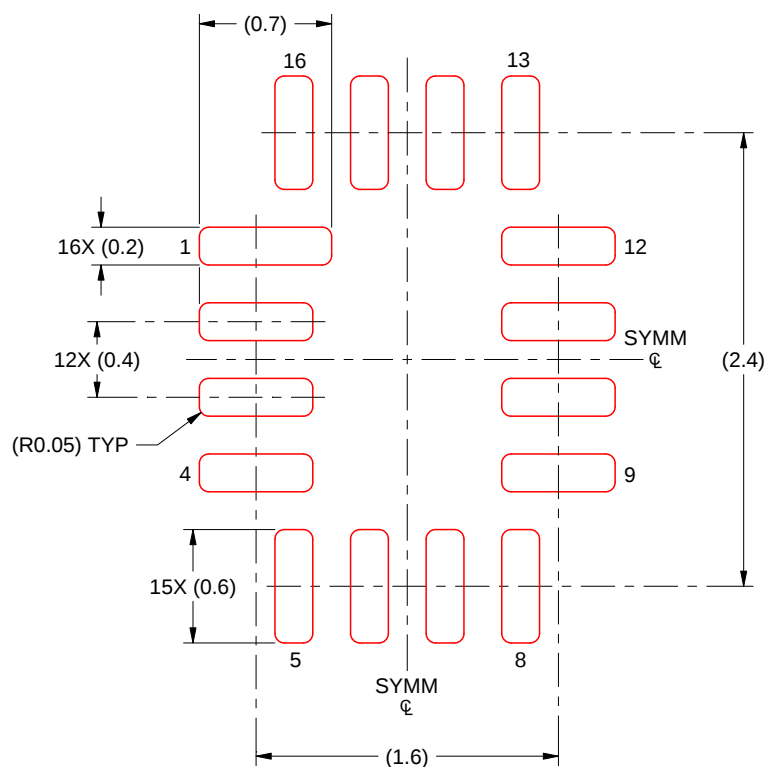
3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

EXAMPLE STENCIL DESIGN

RSV0016A

UQFN - 0.55 mm max height

ULTRA THIN QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
 BASED ON 0.125 MM THICK STENCIL
 SCALE: 25X

4220314/C 02/2020

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



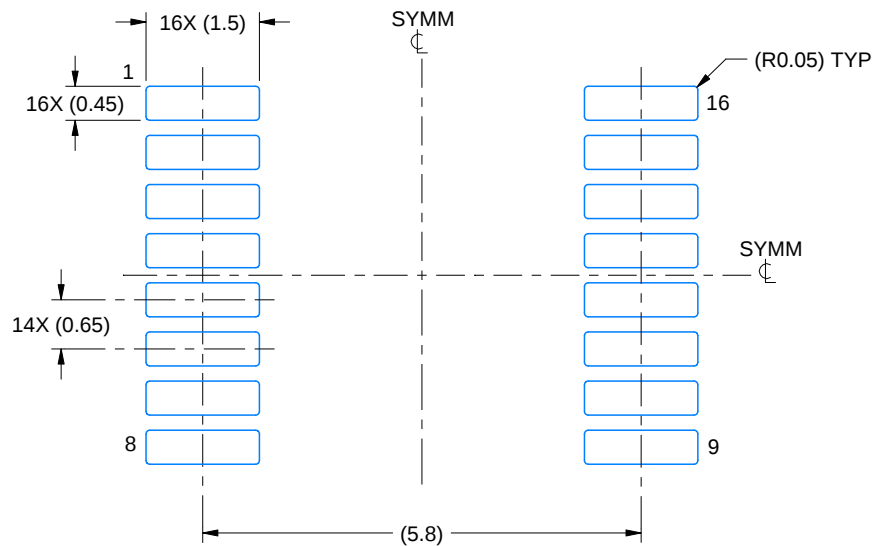
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

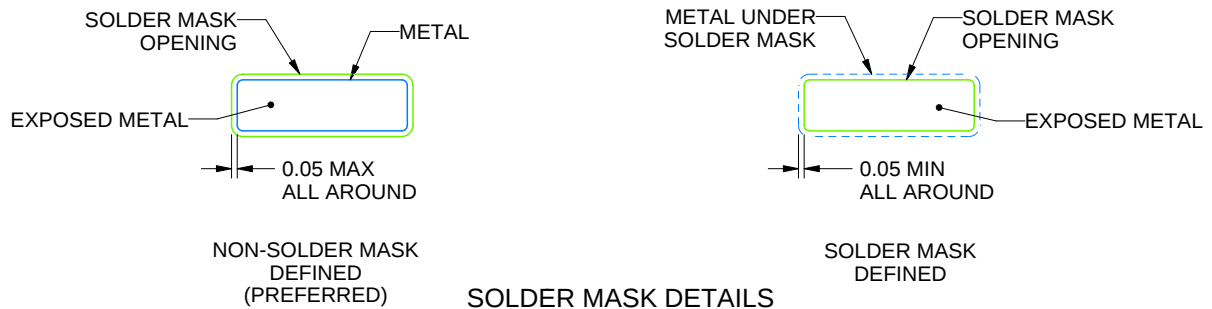
PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



4220204/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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